

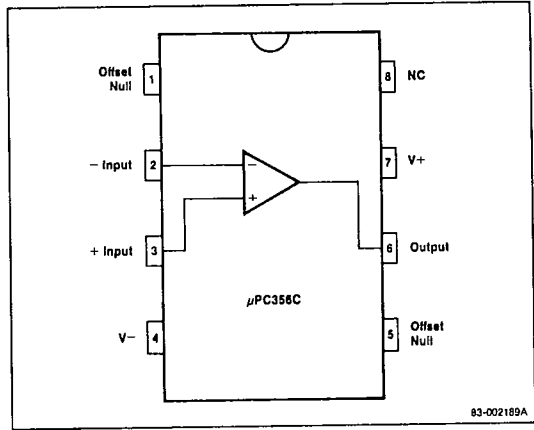
### Description

The  $\mu$ PC356 is a J-FET input operational amplifier with matched P-channel ion implanted J-FETs. In addition to the obvious advantages of J-FET inputs, the  $\mu$ PC356 is designed for high slew rate, wide bandwidth, and extremely fast settling time.

### Features

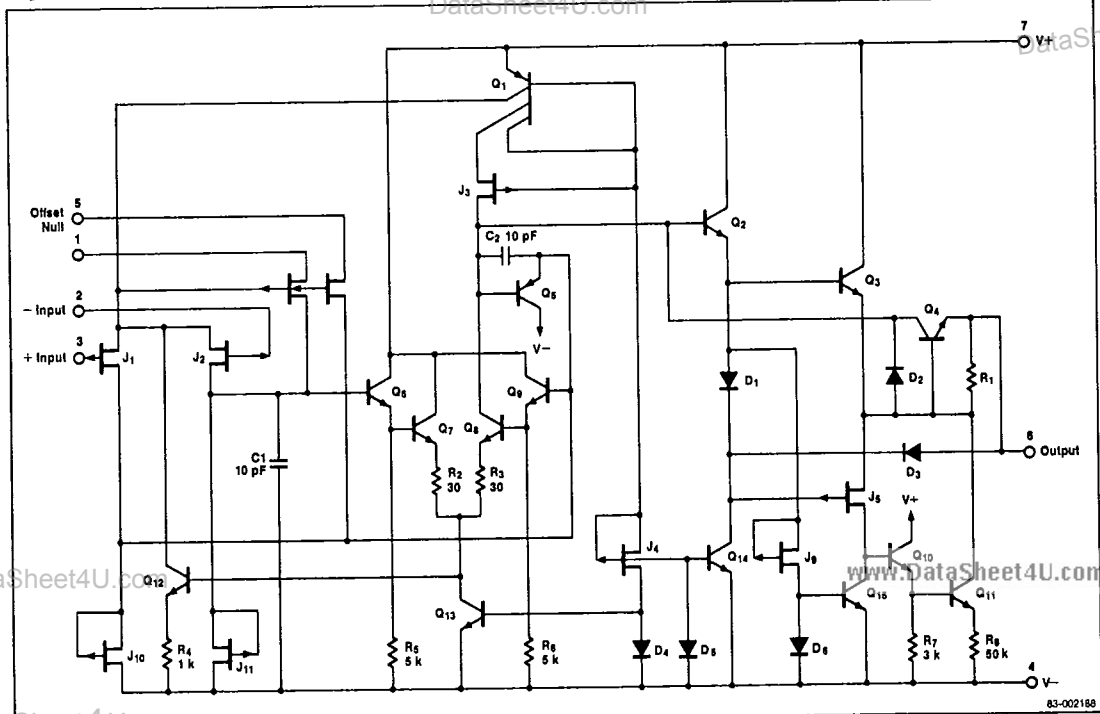
- Low input offset voltage: 5 mV max (trimming technique used)
- Offset adjust does not degrade drift or CMRR
- The NPN sink output stage allows use of large capacitive loads (10,000 pF) without a stability problem
- Internal compensation and large differential input voltage capability
- LF356 equivalent

### Pin Configuration



83-002189A

### Equivalent Circuit



83-002188

**Ordering Information**

Part Number	Package	Operating Temperature Range
μPC356C	Plastic DIP	0°C to +70°C

**Electrical Characteristics** $T_A = 25^\circ\text{C}$ ,  $V_{\pm} = \pm 15\text{V}$ 

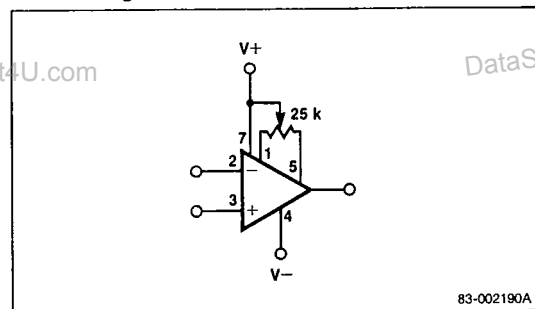
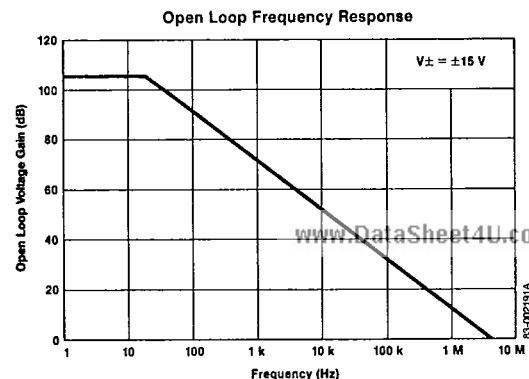
Parameter	Symbol	Limits			Unit	Test Conditions
		Min.	Typ.	Max.		
Input Offset Voltage	$V_{IO}$	2	5		mV	$R_S \leq 50\ \Omega$
Input Offset Current	$I_{IO}$	3	50		pA	
Input Bias Current	$I_b$	30	200		pA	
Large Signal Voltage Gain	$A_{VOL}$	88	106		dB	$R_L \geq 2\ \text{k}\Omega$ , $V_O = \pm 10\ \text{V}$
Supply Current	$I_{CC}$	5	10		mA	
Common Mode Rejection Ratio	CMRR	80	100		dB	
Supply Voltage Rejection Ratio	SVRR	80	100		dB	
Output Voltage Swing	$V_{OH}$	$\pm 12$	$\pm 13$		V	$R_L \geq 10\ \text{k}\Omega$
		$\pm 10$	$\pm 12$		V	$R_L \geq 2\ \text{k}\Omega$
Common Mode Voltage	$V_{ICM}$	$\pm 10$	$\pm 15.1$		V	
Slew Rate	SR	12			$\text{V}/\mu\text{s}$	Rise
		20			$\text{V}/\mu\text{s}$	Fall
Input Noise Voltage	$e_n$	20			$\text{nV}/\sqrt{\text{Hz}}$	$f = 1\ \text{kHz}$ , $R_L = 100\ \Omega$
Gain Bandwidth Products	GBW	5			MHz	
<b>Over Operating Temperature Range</b>						
Input Offset Voltage	$V_{IO}$		7		mV	$R_S \leq 50\ \Omega$ , $T_A = T_{OPT}$
Offset Voltage Drift	$\Delta V_{IO}/\Delta T$		5		$\mu\text{V}/^\circ\text{C}$	$T_A = T_{OPT}$
Input Bias Current	$I_b$		8		nA	$T_A = T_{OPT}$
Input Offset Current	$I_{IO}$		2		nA	$T_A = T_{OPT}$

**Absolute Maximum Ratings** $T_A = 25^\circ\text{C}$ 

Voltage Between $V^+$ and $V^-$	36 V
Power Dissipation	350 mW
Differential Input Voltage	$\pm 30\ \text{V}$
Input Voltage (Note 1)	$\pm 15\ \text{V}$
Output Short Circuit Duration	Indefinite
Operating Temperature Range	0 to +70°C
Storage Temperature Range	-55 to +125°C

Note 1. For supply voltages less than  $\pm 15\ \text{V}$ , the absolute maximum input voltage is equal to the supply voltage.

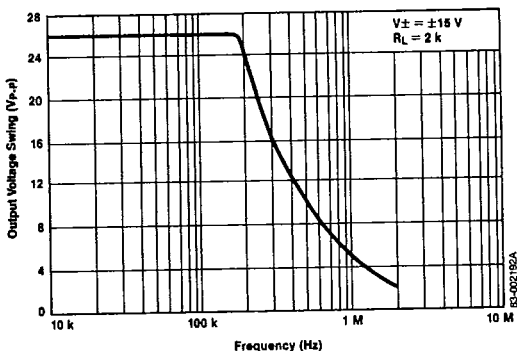
Comment: Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Typical Application****Offset Voltage Null Circuit****Operating Characteristics** $T_A = 25^\circ\text{C}$ 

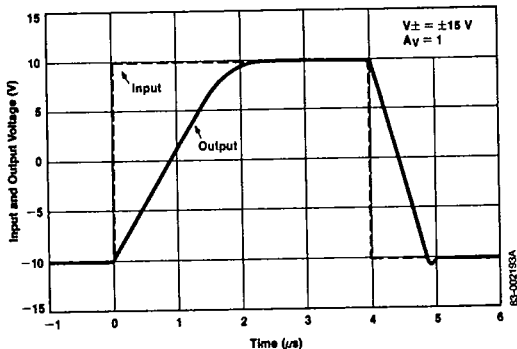
### Operating Characteristics (Cont.)

$T_A = 25^\circ\text{C}$

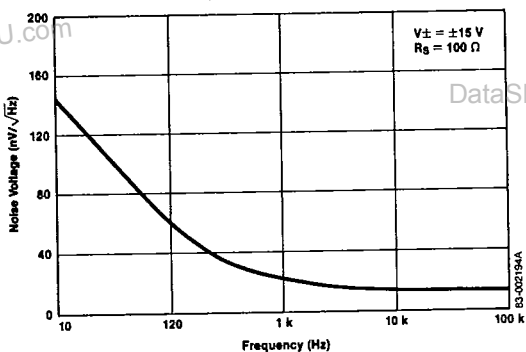
Undistorted Output Voltage Swing



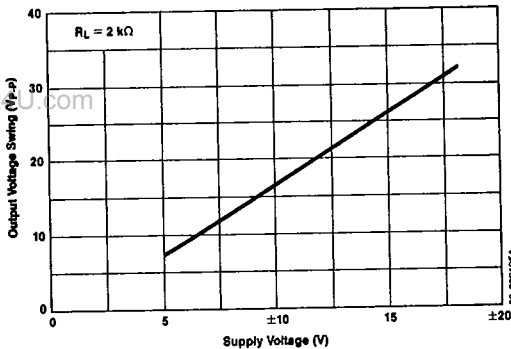
Voltage Follower Pulse Response



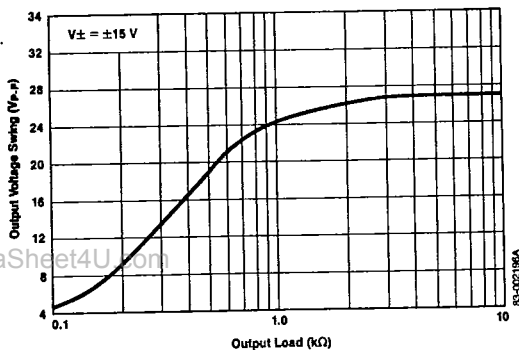
Input Equivalent Noise



Voltage Swing



Voltage Swing



Input Bias Current

